

Vishay General Semiconductor

Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.47 \text{ V}$ at $I_F = 10 \text{ A}$



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 30 A			
V_{RRM}	100 V			
I _{FSM}	350 A			
E _{AS} at L = 180 mH	700 mJ			
V_F at $I_F = 30 A$	0.66 V			
T _J max.	150 °C			
Package	TO-3PW			
Diode variations	Dual common cathode			

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses

High efficiency operation

ROHS COMPLIANT HALOGEN

- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICAL DATA

Case: TO-3PW

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and

commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

PARAMETER	SYMBOL	V60100PW	UNIT			
PANAIVIETEN		STINIBUL	VOOTOOPVV	UNIT		
Maximum repetitive peak reverse voltage		V_{RRM}	100	V		
Maximum average forward rectified current (fig. 1)	per device	_	60	^		
	per diode	I _{F(AV)}	30	A		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	350	А		
Non-repetitive avalanche energy at $T_J = 25$ °C, $L = 180$	E _{AS}	700	mJ			
Peak repetitive reverse current at t_p = 2 μ s, 1 kHz, T_J = 38 °C \pm 2 °C per diode				I _{RRM}	1.0	А
Voltage rate of change (rated V _R)		dV/dt	10 000	V/µs		
Operating junction and storage temperature range		T _J , T _{STG}	-40 to +150	°C		



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Breakdown voltage	I _R = 1.0 mA	T _A = 25 °C	V_{BR}	100 (minimum)	-	V
Instantaneous forward voltage per diode	I _F = 10 A	T _A = 25 °C	V _F ⁽¹⁾	0.52	-	
	I _F = 15 A			0.58	-	
	I _F = 30 A			0.75	0.86	
	I _F = 10 A	T _J = 125 °C		0.47	-	
	I _F = 15 A			0.54	-	
	I _F = 30 A			0.66	0.74	
Reverse current per diode	V _R = 80 V	T _A = 25 °C	I _R ⁽²⁾	35	-	μΑ
		T _A = 125 °C		10	-	mA
	V _R = 100 V	T _A = 25 °C		-	1000	μΑ
		T _A = 125 °C		19	66	mA

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER		SYMBOL	V60100PW	UNIT		
Typical thermal resistance	per diode	$R_{ hetaJC}$	1.5	°C/W		
	per device		0.8			

ORDERING INFORMATION (Example)							
PACKAGE PREFERRED P/N U		UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-3PW	V60100PW-M3/4W	4.5	4W	30/tube	Tube		

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

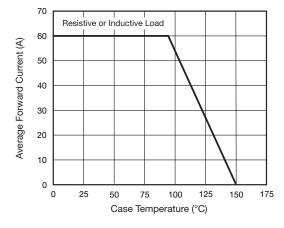


Fig. 1 - Forward Current Derating Curve

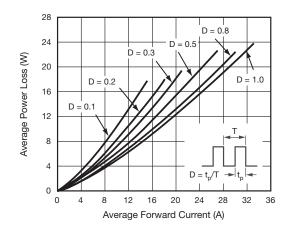


Fig. 2 - Forward Power Loss Characteristics Per Diode



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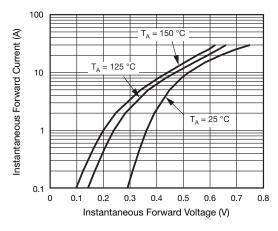


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

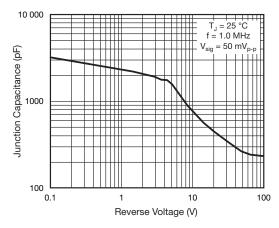


Fig. 5 - Typical Junction Capacitance Per Diode

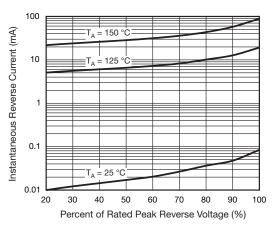


Fig. 4 - Typical Reverse Characteristics Per Diode

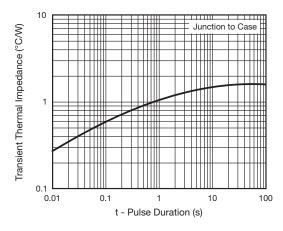
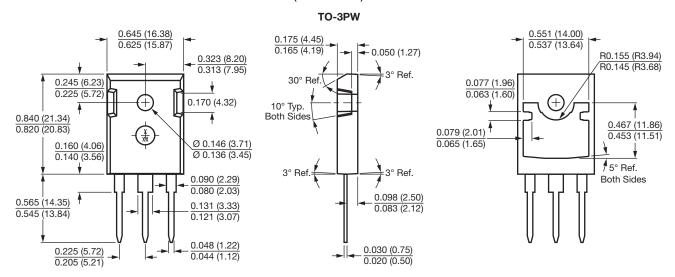


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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